

MOSPEC

FAST NPN SWITCHING TRANSISTOR

high speed transistors suited for low voltage application:

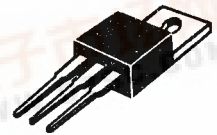
- * High Frequency and Efficiency Converters
- * Switching Regulators
- * Motor Control

FEATURES

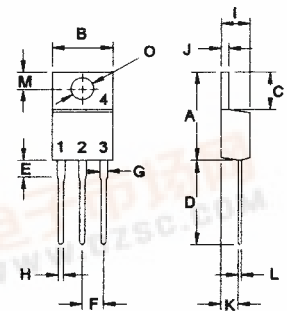
- * Low Saturation Voltage
- * Fast Turn-on and Turn-off

**NPN
BUV28**

**10 AMPERE
POWER TRANSISTOR
NPN SILICON
200 VOLTS
70 WATTS**



TO-220



PIN 1.BASE
2.COLLECTOR
3.EMITTER
4.COLLECTOR(CASE)

DIM	MILLIMETERS	
	MIN	MAX
A	14.68	15.31
B	9.78	10.42
C	5.01	6.52
D	13.06	14.62
E	3.57	4.07
F	2.42	3.66
G	1.12	1.36
H	0.72	0.96
I	4.22	4.98
J	1.14	1.38
K	2.20	2.97
L	0.33	0.55
M	2.48	2.98
O	3.70	3.90

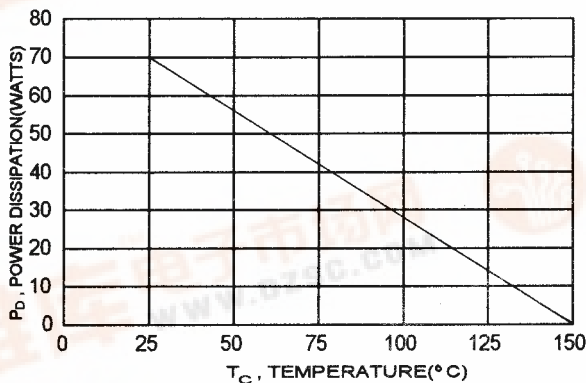
MAXIMUM RATINGS

Characteristic	Symbol	Rating	Unit
Collector-Emitter Voltage	V_{CEO}	200	V
Collector-Base Voltage	V_{CBO}	400	V
Emitter-Base Voltage	V_{EBO}	7.0	V
Collector Current - Continuous	I_C	10	A
Base Current-Continuous	I_B	2.0	A
Total Power Dissipation @ $T_C = 25^\circ C$ Derate above $25^\circ C$	P_D	70 0.56	W W/ $^\circ C$
Operating and Storage Junction Temperature Range	T_J, T_{STG}	-65 to +150	$^\circ C$

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance Junction to Case	$R_{\theta jc}$	1.785	$^\circ C/W$

FIGURE -1 POWER DERATING



ELECTRICAL CHARACTERISTICS ($T_c = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
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OFF CHARACTERISTICS

Collector-Emitter Breakdown Voltage ($I_c = 30\text{ mA}$, $I_B = 0$)	$V_{(BR)CEO}$	200		V
Collector Cutoff Current ($V_{CB} = 300\text{ V}$, $I_E = 0$)	I_{CBO}		1.0	mA
Emitter Cutoff Current ($V_{EB} = 5.0\text{ V}$, $I_C = 0$)	I_{EBO}		1.0	mA

ON CHARACTERISTICS (1)

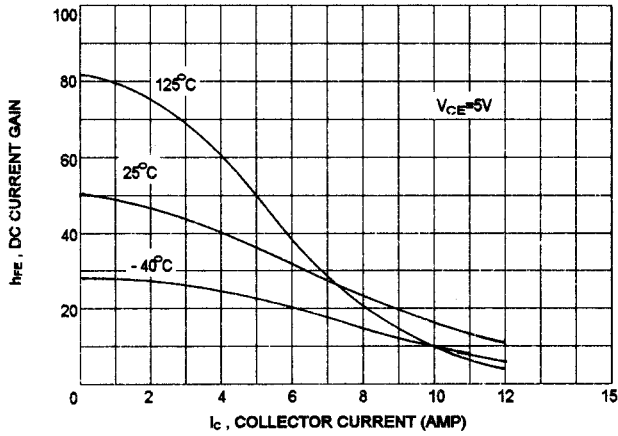
Collector-Emitter Saturation Voltage ($I_c = 3.0\text{ A}$, $I_B = 300\text{ mA}$) ($I_c = 6.0\text{ A}$, $I_B = 600\text{ mA}$)	$V_{CE(sat)}$		0.7 1.5	V
Base-Emitter Saturation Voltage ($I_c = 6.0\text{ A}$, $I_B = 600\text{ mA}$)	$V_{BE(sat)}$		2.0	V

SWITCHING CHARACTERISTICS

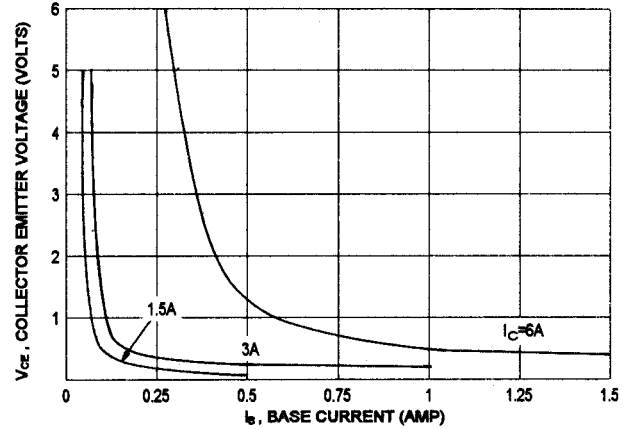
Turn-On Time	$V_{CC} = 150\text{V}$, $I_C = 5.0\text{A}$ $I_{B1} = -I_{B2} = 0.5\text{A}$	t_{on}	1.0	us
Storage Time		t_s	1.5	us
Fall Time		t_f	0.3	us

(1) Pulse Test: Pulse width $\leq 300\text{ us}$, Duty Cycle $\leq 2.0\%$

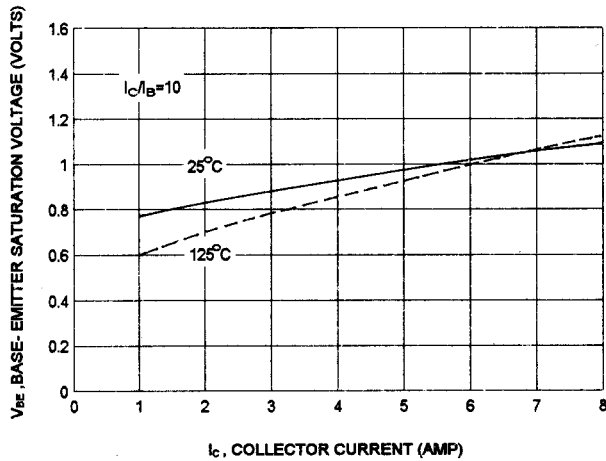
DC CURRENT GAIN



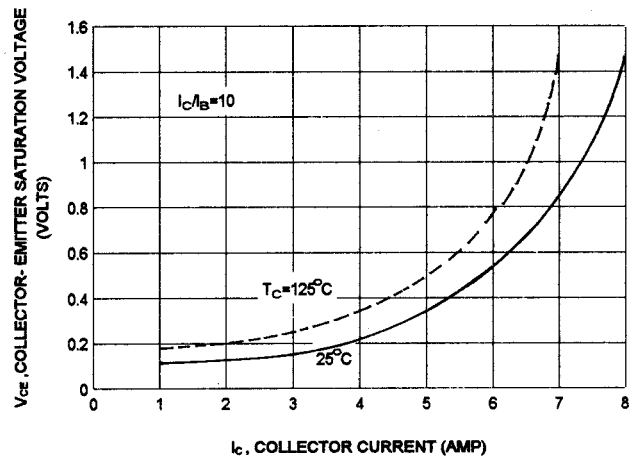
COLLECTOR SATURATION REGION



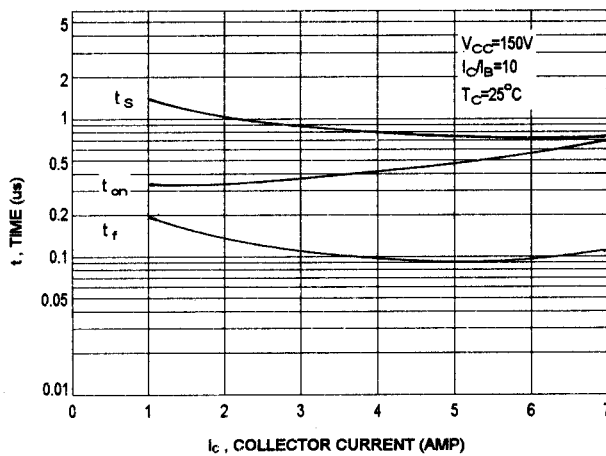
BASE-EMITTER SATURATION VOLTAGE



COLLECTOR-EMITTER SATURATION VOLTAGE



SWITCHING TIME



ACTIVE-REGION SAFE OPERATING AREA

